

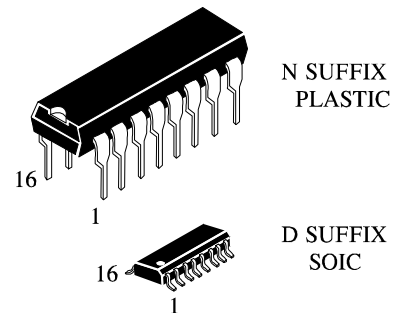
+5V-Powered, Multichannel RS-232

Drivers / Receivers

MAX232 is purposed for application in high-performance information processing systems and control devices of wide application.

Input voltage levels are compatible with standard CMOS levels.

- Output voltage levels are compatible with input levels of K-MOS, N-MOS and TTL integrated circuits.
- Supply voltage : 5V
- Low input current: 1.0 μA ; 0.1 μA at $T = 25^\circ\text{C}$.
- Output current 24 mA.
- Latching current not less than 450 mA at $T = 25^\circ\text{C}$
- The transmitter outputs and receiver inputs are protected to $\pm 15\text{kV}$ Air ESD.



ORDERING INFORMATION

MAX232CPE Plastic DIP

MAX232CSE SOIC

MAX232CWE SOIC

T_A MAX232CWE⁰ C

For all packages

Truth table

Inputs	Outputs
R_{IN}, T_{IN}	R_{OUT}, T_{OUT}
H	L
L	H
Note - H – voltage high level; L – low voltage level	

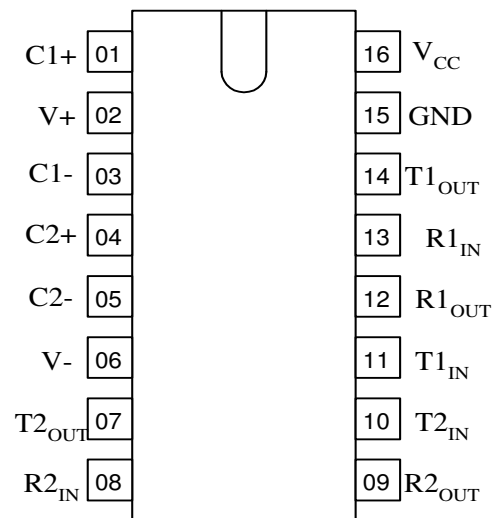


Table of pin description

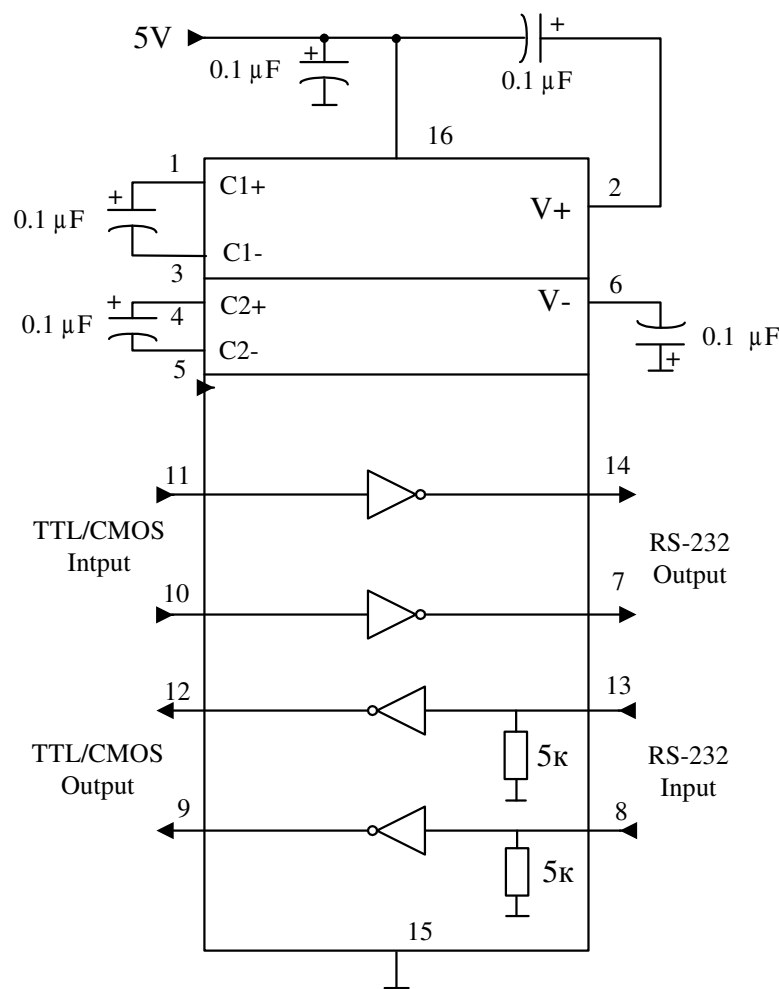
Pin No.	Symbol	Pin name
01	C1+	Output of external capacitance of positive voltage multiplier unit
02	V+	Output of positive voltage of multiplier unit
03	C1-	Output of external capacitance of positive voltage multiplier unit
04	C2+	Output of external capacitance of negative voltage multiplier unit
05	C2-	Output of external capacitance of negative voltage multiplier unit
06	V-	Output of negative voltage of multiplier unit
07	T2 _{OUT}	Output of transmitter data (levels RS – 232)
08	R2 _{IN}	Input of receiver data (levels RS – 232)
09	R2 _{OUT}	Output of receiver data (levels TTL/KMOS)
10	T2 _{IN}	Input of transmitter data (levels TTL/KMOS)
11	T1 _{IN}	Input of transmitter data (levels TTL/KMOS)
12	R1 _{OUT}	Output of receiver data (levels TTL/KMOS)
13	R1 _{IN}	Input of receiver data (levels RS – 232)
14	T1 _{OUT}	Output of transmitter data (levels RS – 232)
15	GND	Common output
16	V _{CC}	Supply output of voltage source

Maximum conditions

Symbol	Parameter	Rate		Unit
		min	max	
V _{CC}	Supply voltage	-0.3	6.0	V
V+	Transmitter high output voltage	V _{CC} -0.3	14	
V-	Transmitter low output voltage	-0.3	-14	
V _{TIN}	Transmitter input voltage	-0.3	V+ +0.3	
V _{RIN}	Receiver input voltage	-30	30	
P _D	Dissipated power	-	842 762	mW
	DIP – package			
	SO - package			
I _{SC}	Output current of transmitter short circuit	-	Continuously	mA
T _a	Ambient temperature	-60	150	°C

Recommended Operating Conditions

Symbol	Parameter	Rate		Unit
		min	max	
V_{CC}	Supply voltage	4.5	5.5	V
V_{+}	Transmitter output high voltage	5.0	-	
V_{-}	Transmitter output low voltage	-5.0	-	
V_{TIN}	Transmitter input voltage	0	V_{CC}	
V_{RIN}	Receiver input voltage	-30	30	
I_{SC}	Transmitter short circuit output current	-	± 60	mA
T_a	Ambient temperature	-40	85	$^{\circ}C$



Static parameters

Static parameters							
Symbol	Parameter	Test conditions	Rate				Unit
			25°C		-40 °C to 85 °C		
			min	max	min	max	
I _{CC}	Consumption current static	V _{CC} =5.0 V V _{IL} = 0 V	-	10.0	-	14.0 *	mA

Receiver electrical parameters

V_h	Hysteresis voltage	$V_{CC}=5.0\text{ V}$	0.2	0.9	0.2	1.0	V
V_{On}	On (operation) voltage	$V_O \leq 0.1\text{ V}$ $I_{OL} \leq 20\text{ uA}$	-	2.4	-	2.3	
V_{off}	Off (dropout) voltage	$V_O \geq V_{CC}-0.1\text{ V}$ $I_{OH} \leq -20\text{ uA}$	0.8	-	0.9	-	
V_{OL}	Output low voltage	$I_{OL} = 3.2\text{ mA}$ $V_{CC} = 4.5\text{ V}$ $V_{IH} = 2.4\text{ V}$	-	0.3	-	0.4	
V_{OH}	Output high voltage	$I_{OH} = -1.0\text{ mA}$ $V_{CC} = 4.5\text{ V}$ $V_{IL} = 0.8\text{ V}$	3.6	-	3.5	-	
R_I	Input resistance	$V_{CC} = 5.0\text{ V}$	3.0	7.0	3.0	7.0	kOhm

Transmitter electrical parameters

V_{OL}	Output low voltage	$V_{CC} = 4.5\text{ V}$ $V_{IH} = 2.0\text{ V}$ $R_L = 3.0\text{ kOhm}$	-	-5.2	-	-5.0	V
V_{OH}	Output high voltage	$V_{CC} = 4.5\text{ V}$ $V_{IL} = 0.8\text{ V}$ $R_L = 3.0\text{ kOhm}$	5.2	-	5.0	-	
I_{IL}	Input low current	$V_{CC}=5.5\text{ V}$ $V_{IL}=0\text{ V}$	-	-1.0	-	-10.0	uA
I_{IH}	Input high current	$V_{CC}=5.5\text{ V}$ $V_{IH}=V_{CC}$		1.0		10.0	
SR	Speed of output front change	$V_{CC}=5.0\text{ V}$ $C_L=50 - 1000\text{ pF}$ $R_L = 3.0 - 7.0\text{ kOhm}$	3.0	30	2.7	27	V/ μ s
R_O	Output resistance	$V_{CC} = V_+ = V_- = 0\text{ V}$ $V_O = \pm 2\text{ V}$	350	-	300	-	Ohm
I_{SC}	Short circuit output current	$V_{CC}=5.5\text{ V}$ $V_O = 0\text{ V}$ $V_I = V_{CC}$ $V_I = 0\text{ V}$		-50 50		-60 60	mA
ST	Speed of information transmission	$V_{CC}=4.5\text{ V}$ $C_L = 1000\text{ pF}$ $R_L = 3.0\text{ kOhm}$ $t_w = 7\text{ us}$ (for extreme $-t_w = 8\text{ us}$)	140	-	120	-	kbps

Dynamic parameters

Symbol	Parameter	Test conditions	Rate				Unit
			25 °C		from -40 °C to 85 °C		
			min	max	min	max	
t _{PHLR} (t _{PLHR})	Signal propagation delay time when switching on (off)	V _{CC} = 4.5 V C _L = 150 pF V _{IL} = 0 V V _{IH} = 3.0 V t _{LH} = t _{HL} ≤ 10 ns	-	9.7	-	10	us
t _{PHLT} (t _{PLHT})	Signal propagation delay time when switching on (off)	V _{CC} = 4.5 V C _L = 2500 pF V _{IL} = 0 V V _{IH} = 3.0 V R _L = 3 kOhm t _{LH} = t _{HL} ≤ 10 ns		5.0 *		6.0 *	

Capacitance

Symbol	Parameter	V_{CC} ,	Rate	Unit
C_{IN}	Input capacitance	5.0	9.0	pF
C_{PD}	Dynamic capacitance		90	

Timing diagram when measuring IC dynamic parameters

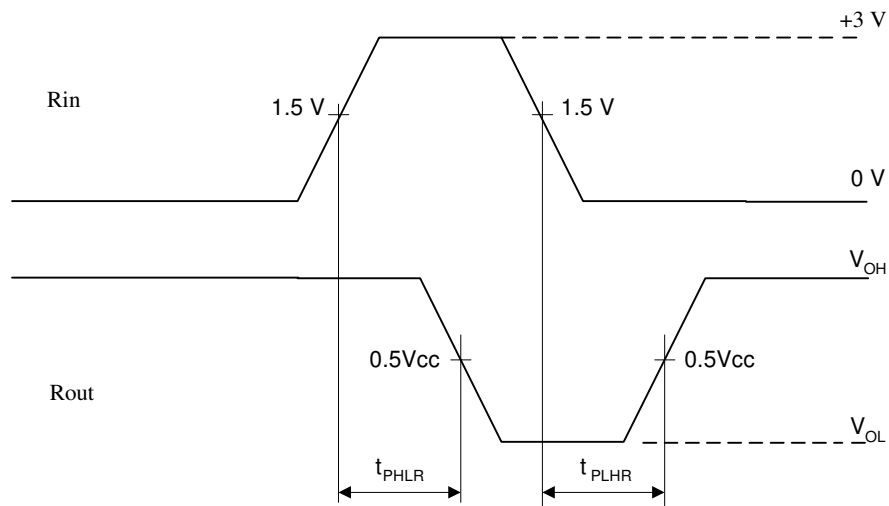


Figure 3

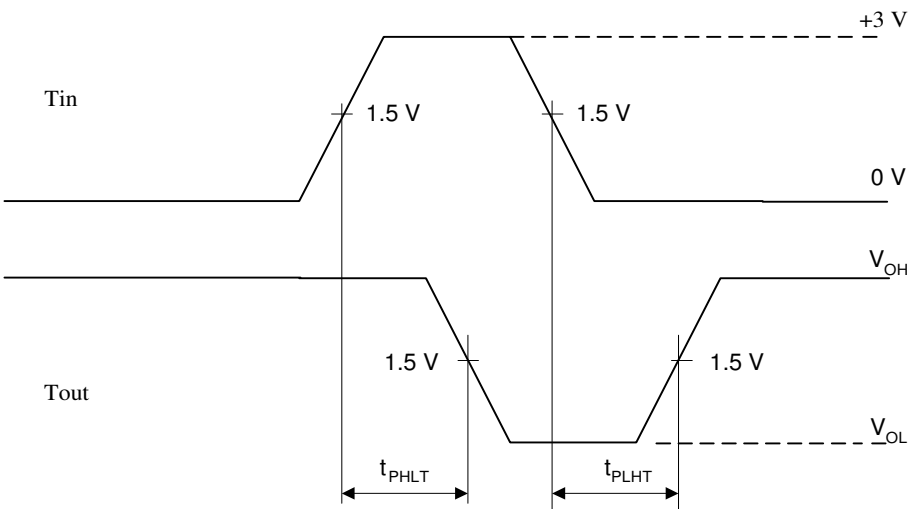


Figure 4

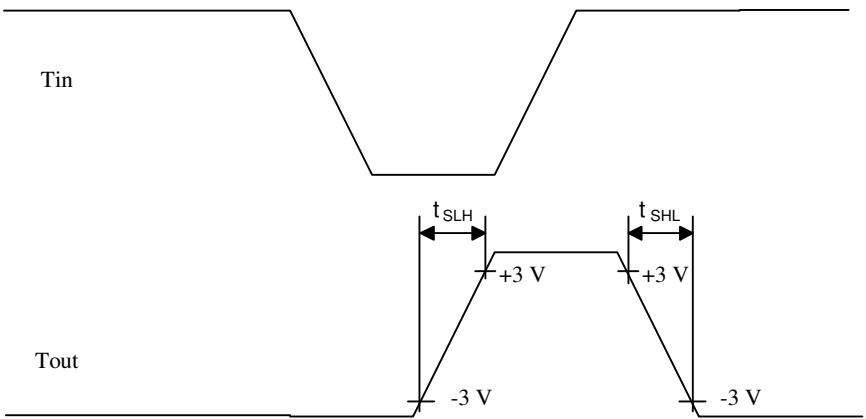


Figure 5

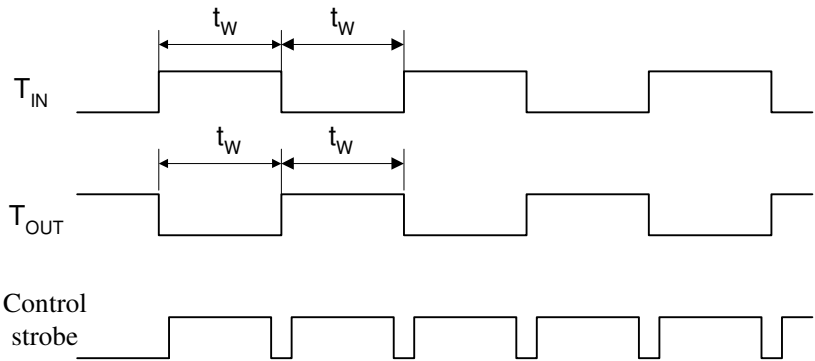
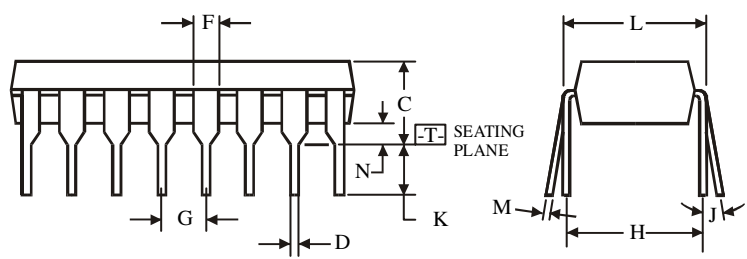
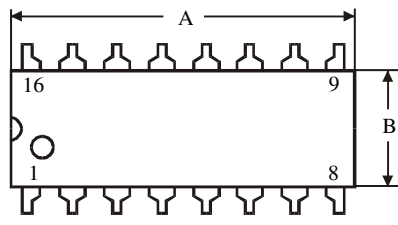


Figure 6

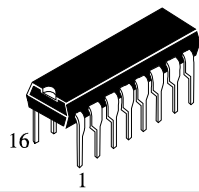
N SUFFIX PLASTIC DIP
(MS - 001BB)



⊕ 0.25 (0.010) M T

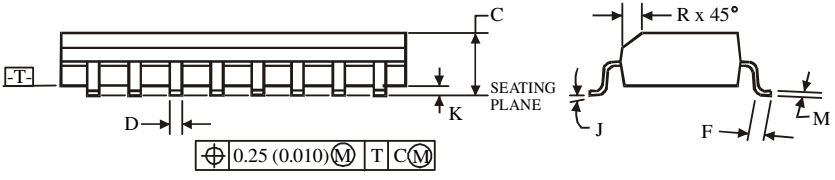
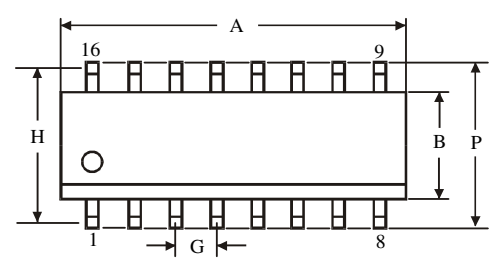
NOTES:

1. Dimensions “A”, “B” do not include mold flash or protrusions.
Maximum mold flash or protrusions 0.25 mm (0.010) per side.



Symbol	Dimension, mm	
	MIN	MAX
A	18.67	19.69
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

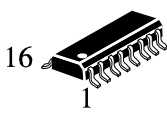
D SUFFIX SOIC
(MS - 012AC)



⊕ 0.25 (0.010) M T C M

NOTES:

1. Dimensions A and B do not include mold flash or protrusion.
2. Maximum mold flash or protrusion 0.15 mm (0.006) per side
for A; for B - 0.25 mm (0.010) per side.



Symbol	Dimension, mm	
	MIN	MAX
A	9.8	10
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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